

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	26811	temperature same (memory chip semiconductor) same sens\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/08 15:04
L2	3864	L1 and (sens\$3 with voltage with temperature)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/08 14:56
L3	31	L2 and (comparator same (sens\$3 with voltage) same (temperature with signal)) and potentiometer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/08 14:56
L4	28	((temperature thermal heat) with (memory chip semiconductor)) and (sens\$3 with voltage with temperature) and (comparator same (sens\$3 with voltage) same (temperature with signal)) and potentiometer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/08 15:22
L5	3	((temperature thermal heat) with (access with memory)) and (sens\$3 with voltage with temperature) and (comparator same (sens\$3 with voltage) same (temperature with signal)) and potentiometer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/08 15:26
S1	0	10/672246	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/06 09:01
S2	2	"6612738".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/06 10:52
S3	26784	temperature same (memory chip semiconductor) same sens\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/06 10:54

S4	3861	S3 and (sen\$3 with voltage with temperature)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/06 10:55
S6	156	S4 and (comparator same (sens\$3 with voltage) same (temperature with signal))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/08 13:11
S7	44	S6 and (logic same (temperature with signal))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/06 10:59
S8	41	S7 and (reference with voltage)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/06 10:59
S9	35	S8 and switch	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/06 11:00
S10	0	S9 and trimmer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/06 11:12
S11	9	S9 and (adjust\$3 with reference with voltage)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/06 11:01
S12	2	S6 and trimmer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/06 11:12

S13	2513	(comparator same (sens\$3 with voltage) same (sens\$3 with temperature))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/06 15:28
S14	291	S13 and ((reference with temperature) same (reference with voltage) same (compar\$3 with sen\$3 with voltage))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/06 11:25
S15	0	S14 and (trimmer same adjust\$3 same (reference with voltage))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/06 11:25
S16	1	S14 and (trimmer same (reference with voltage))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/06 12:06
S18	26784	temperature same (memory chip semiconductor) same sens\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/06 12:07
S19	3861	S18 and (sen\$3 with voltage with temperature)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/06 12:07
S20	156	S19 and (comparator same (sens\$3 with voltage) same (temperature with signal))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/06 12:07
S21	2	S20 and trimmer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/06 12:09

S23	0	S21 and (adjust\$3 same (reference with voltage))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/06 12:09
S24	33	((comparator same (sens\$3 with voltage) same (indicat\$4 with sens\$3 with temperature))) and (adjust\$3 with reference with voltage)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/06 15:36
S25	0	S24 and trimmer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/06 15:33
S26	5	S24 and (offset with voltage)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/06 15:34
S27	13	((comparator same (sens\$3 with voltage) same (indicat\$4 adj5 sens\$3 adj5 temperature))) and (adjust\$3 with reference with voltage)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/06 18:04
S28	1	S27 and (compar\$3 with reference with voltage with sens\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/06 15:43
S29	3	((comparator same (sens\$3 with voltage) same (indicat\$4 adj5 sens\$3 adj5 temperature))) and (adjust\$3 with reference with voltage) and (comparing with voltage)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/08 09:51
S30	0	(random with memory) and ((comparator same (sens\$3 with voltage) same (indicat\$4 adj5 sens\$3 adj5 temperature))) and (comparing with voltage)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/07 17:03

S31	3	memory and ((comparator same (sens\$3 with voltage) same (indicat\$4 adj5 sens\$3 adj5 temperature))) and (comparing with voltage)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/07 16:59
S32	12	("3158027" "3440883" "4476357" "4726226" "4847794" "5024535" "5844208" "5918982" "5961215" "6149299").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2004/12/08 13:06
S33	0	S32 and trimmer	US-PGPUB; USPAT; USOCR	OR	ON	2004/12/07 17:03
S34	0	S32 and ((comparator same (sens\$3 with voltage) same (sens\$3 adj5 temperature))) and (comparing with voltage)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/07 17:03
S35	3	((comparator same (sens\$3 with voltage) same (indicat\$4 adj5 sens\$3 adj5 (temperature heat thermal)))) and (adjust\$3 with reference with voltage) and (comparing with voltage)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/07 17:22
S36	0	((comparator same voltage same (indicat\$4 adj5 sens\$3 adj5 (temperature heat thermal)))) and ((adjust\$3 preset) with (input adj2 offset adj voltage)) and (comparing with voltage)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/07 17:27
S37	0	((comparator same voltage same (indicat\$4 adj5 sens\$3 adj5 (temperature heat thermal)))) and ((adjust\$3 preset) with input with offset with voltage) and (comparing with voltage)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/07 17:28
S38	13	(resistor same (adjust\$3 preset\$4) same (reference with voltage)) and ((comparator with voltage) same (indicat\$4 adj5 temperature)) and (comparing with reference with voltage)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/07 17:33
S39	2	S38 and ((semiconductor chip (random with access with memory)) same (temperature with (sens\$3 circuit)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/07 17:41

S40	13	S38 and (temperature with (sens\$3 circuit))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/07 17:42
S41	1	((comparator same (sens\$3 with voltage) same (indicat\$4 adj5 sens\$3 adj5 temperature))) and (adjust\$3 with reference with voltage) and (comparing with voltage) and logic	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/08 10:57
S42	2	(comparator same (sens\$3 with voltage)) and (indicat\$4 adj5 sens\$3 adj5 temperature) and (adjust\$3 with reference with voltage) and (comparing with voltage) and (random adj access adj memory)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/08 11:00
S43	26811	temperature same (memory chip semiconductor) same sens\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/08 13:23
S44	3864	S43 and (sen\$3 with voltage with temperature)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/08 13:23